# **Central**<sup>™</sup> Semiconductor Corp.

145 Adams Ave., Hauppauge, NY 11788 USA Phone (631) 435-1110 FAX (631) 435-1824

Manufacturers of World Class Discrete Semiconductors www.centralsemi.com MJE13005

NPN SILICON POWER TRANSISTOR

JEDEC TO-220 CASE

#### **DESCRIPTION**

The CENTRAL SEMICONDUCTOR MJE13005 is a Silicon NPN Power Transistor, designed for high speed power switching applications.

## MAXIMUM RATINGS (T<sub>C</sub>=25°C unless otherwise noted)

	<u>SYMBOL</u>		<u>UNITS</u>
Collector-Emitter Voltage	$V_{CEO}$	400	V
Collector-Emitter Voltage	$V_{CEV}$	700	V
Emitter-Base Voltage	$V_{EBO}$	9.0	V
Collector Current	IC	4.0	Α
Peak Collector Current	I <sub>CM</sub>	8.0	Α
Base Current	$I_{B}$	2.0	Α
Peak Base Current	I <sub>BM</sub>	4.0	Α
Emitter Current	ΙΕ	6.0	Α
Peak Emitter Current	I <sub>EM</sub>	12	Α
Power Dissipation (T <sub>A</sub> =25°C)	$P_{D}$	2.0	W
Power Dissipation	$P_{D}$	75	W
Operating and Storage Junction Temperature	$T_{J}, T_{stg}$	-65 to +150	°C
Thermal Resistance	ΘJA	62.5	°C/W
Thermal Resistance	ΘJC	1.67	°C/W

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C unless otherwise noted)

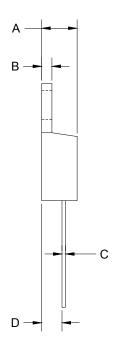
<u>SYMBOL</u>	TEST CONDITIONS	MIN	MAX	<u>UNITS</u>
I <sub>CEV</sub>	V <sub>CE</sub> =700V, V <sub>BE(OFF)</sub> =1.5V		1.0	mA
ICEV	V <sub>CE</sub> =700V, V <sub>BE</sub> (OFF)=1.5V, T <sub>C</sub> =100°C		5.0	mA
I <sub>EBO</sub>	V <sub>EB</sub> =9.0V		1.0	mA
BV <sub>CEO</sub>	I <sub>C</sub> =10mA	400		V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =1.0A, I <sub>B</sub> =0.2A		0.5	V
VCE(SAT)	I <sub>C</sub> =2.0A, I <sub>B</sub> =0.5A		0.6	V
VCE(SAT)	I <sub>C</sub> =4.0A, I <sub>B</sub> =1.0A		1.0	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =1.0A, I <sub>B</sub> =0.2A		1.2	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =2.0A, I <sub>B</sub> =0.5A		1.6	V
h <sub>FE</sub> ` ′	V <sub>CE</sub> =5.0V, I <sub>C</sub> =1.0A	10	60	
h <sub>FE</sub>	$V_{CE}$ =5.0V, $I_{C}$ =2.0A	8.0	40	

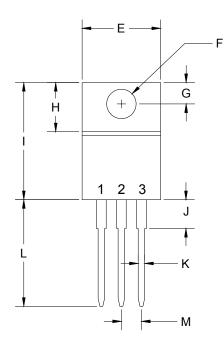
μS

t<sub>fi</sub>

ELECTRICAL CHA	ARACTERISTICS (CONTINUED)				
<u>SYMBOL</u>	TEST CONDITIONS	MIN	<u>TYP</u>	MAX	<u>UNITS</u>
f <sub>T</sub>	$V_{CE}$ =10V, $I_{C}$ =500mA, f=1.0MHz	4.0			MHz
$C_{ob}$	$V_{CB}$ =10V, $I_E$ =0, f=100kHz		130		pF
	Resistive Load				
$t_d$	$V_{CC}$ =125V, $I_{C}$ =2.0A, $I_{B1}$ = $I_{B2}$ =0.4A			0.1	μS
t <sub>r</sub>	t <sub>p</sub> =25µs, Duty Cycle ≤ 1.0%			0.7	μS
$t_{s}$				4.0	μS
t <sub>f</sub>				0.9	μS
	Inductive Load				
t <sub>sv</sub>	I <sub>C</sub> =2.0A, V <sub>clamp</sub> =300V, I <sub>B1</sub> =0.4A,			4.0	μS
t <sub>c</sub>	$V_{BE(off)}$ =5.0V, $T_{C}$ =100°C			0.9	μS

## TO-220 PACKAGE - MECHANICAL OUTLINE





DIMENSIONS					
	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	
Α	0.170	0.190	4.31	4.82	
В	0.045	0.055	1.15	1.39	
С	0.013	0.026	0.33	0.65	
D	0.083	0.107	2.10	2.72	
E	0.394	0.417	10.01	10.60	
F (DIA)	0.140	0.157	3.55	4.00	
G	0.100	0.118	2.54	3.00	
Н	0.230	0.270	5.85	6.85	
I	0.560	0.625	14.23	15.87	
J	ı	0.250	1	6.35	
K	0.025	0.038	0.64	0.96	
L	0.500	0.579	12.70	14.70	
М	0.090	0.110	2.29	2.79	
TO-220 (REV: R2)					

0.16

## Lead Code:

R2

- 1) Base
- 2) Collector
- 3) Emitter

Tab is Common to Pin 2



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- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### **CONTACT US**

#### Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

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